

# isc N-Channel MOSFET Transistor

# IRF3704ZCS

**• FEATURES**

- With TO-263( D2PAK ) packaging
- High speed switching
- Low gate input resistance
- Standard level gate drive
- Easy to use
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

**• APPLICATIONS**

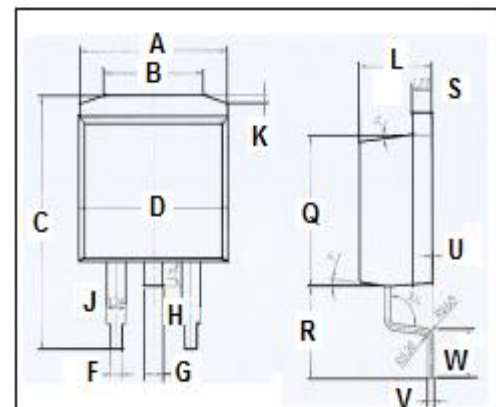
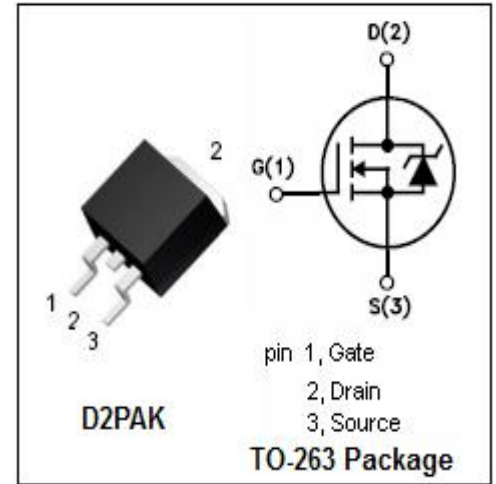
- Power supply
- Switching applications

**• ABSOLUTE MAXIMUM RATINGS(T<sub>a</sub>=25°C)**

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	20	V
V <sub>GSS</sub>	Gate-Source Voltage	±16	V
I <sub>D</sub>	Drain Current-Continuous; T <sub>c</sub> =25°C T <sub>c</sub> =100°C	67 47	A
I <sub>DM</sub>	Drain Current-Single Pulsed	260	A
P <sub>D</sub>	Total Dissipation	57	W
T <sub>j</sub>	Operating Junction Temperature	150	°C
T <sub>stg</sub>	Storage Temperature	-55~175	°C

**• THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th(ch-c)</sub>	Channel-to-case thermal resistance	2.65	°C/W
R <sub>th(ch-a)</sub>	Channel-to-ambient thermal resistance	40	°C/W



DIM	mm	
	MIN	MAX
A	10	
B	6.6	6.8
C	15.23	15.25
D	10.15	10.17
F	0.76	0.78
G	1.26	1.28
H	1.4	1.6
J	1.33	1.35
K	0.4	0.6
L	4.6	4.8
Q	8.69	8.71
R	5.28	5.30
S	1.26	1.28
U	0.0	0.2
V	0.37	0.39
W	2.80	2.82

**isc N-Channel MOSFET Transistor****IRF3704ZCS****ELECTRICAL CHARACTERISTICS**T<sub>C</sub>=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 0.25mA	20			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; I <sub>D</sub> =0.25mA	1.65		2.55	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =21A		6.3	7.9	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> =± 16V; V <sub>DS</sub> = 0V			±0.1	μA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = 16V; V <sub>GS</sub> = 0V; T <sub>C</sub> =25°C V <sub>DS</sub> = 16V; V <sub>GS</sub> = 0V; T <sub>C</sub> =125°C			1 150	μA
V <sub>SDF</sub>	Diode forward voltage	I <sub>SD</sub> =17A, V <sub>GS</sub> = 0 V			1.0	V

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